

NLG4140

12.5 GHz 1 : 2 CLOCK DISTRIBUTOR (AC Coupling)

The NLG4140 is an ultra-fast 1:2 Clock Distributor operating at up to 12.5 GHz (MIN.) . Designed with LSCFL (Low-power Source Coupled FET Logic) , either AC coupling or DC coupling can be used for signal input and outputs .

Owing to built-in 50-ohm termination resistor between signal input pin and ground (GND), external termination resistor is unnecessary for impedance matching.

The NLG4140 is fabricated using the 0.15- μ m gate length A-SAINT (Advanced Self-Aligned Implantation for N⁺ layer Technology) process .

FEATURES

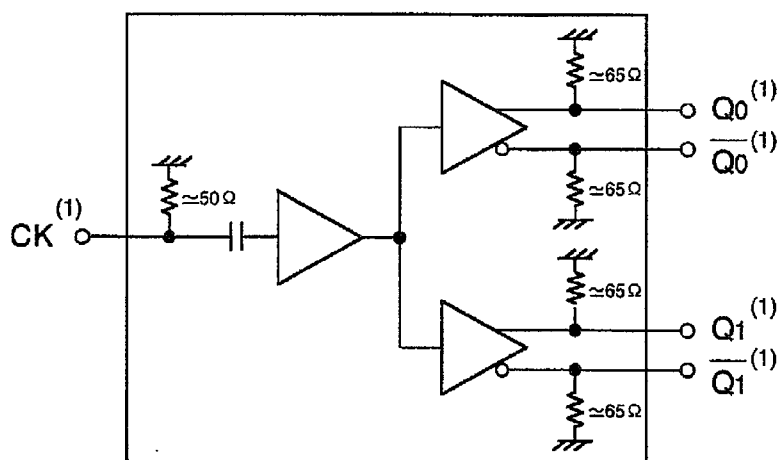
Ultra-high speed : maximum clock Frequency	f_{MAX} : 12.5 GHz	[MIN.]
minimum clock Frequency	f_{MIN} : 2.0 GHz	[MAX.]
output rise time	t_r = 15 ps (20-80 %)	[TYP.]
output fall time	t_f = 15 ps (20-80 %)	[TYP.]

High Reliability : hermetically-sealed package

APPLICATIONS

- Clock distributor
- Reforming of waveform

FUNCTIONAL DIAGRAM



Note (1) DC coupling or AC coupling (see page 9)

TRUTH TABLE

CK	Q_n	$\overline{Q_n}$
H	H	L
L	L	H

Note $Q_n, \overline{Q_n}$: $n = 0, 1$

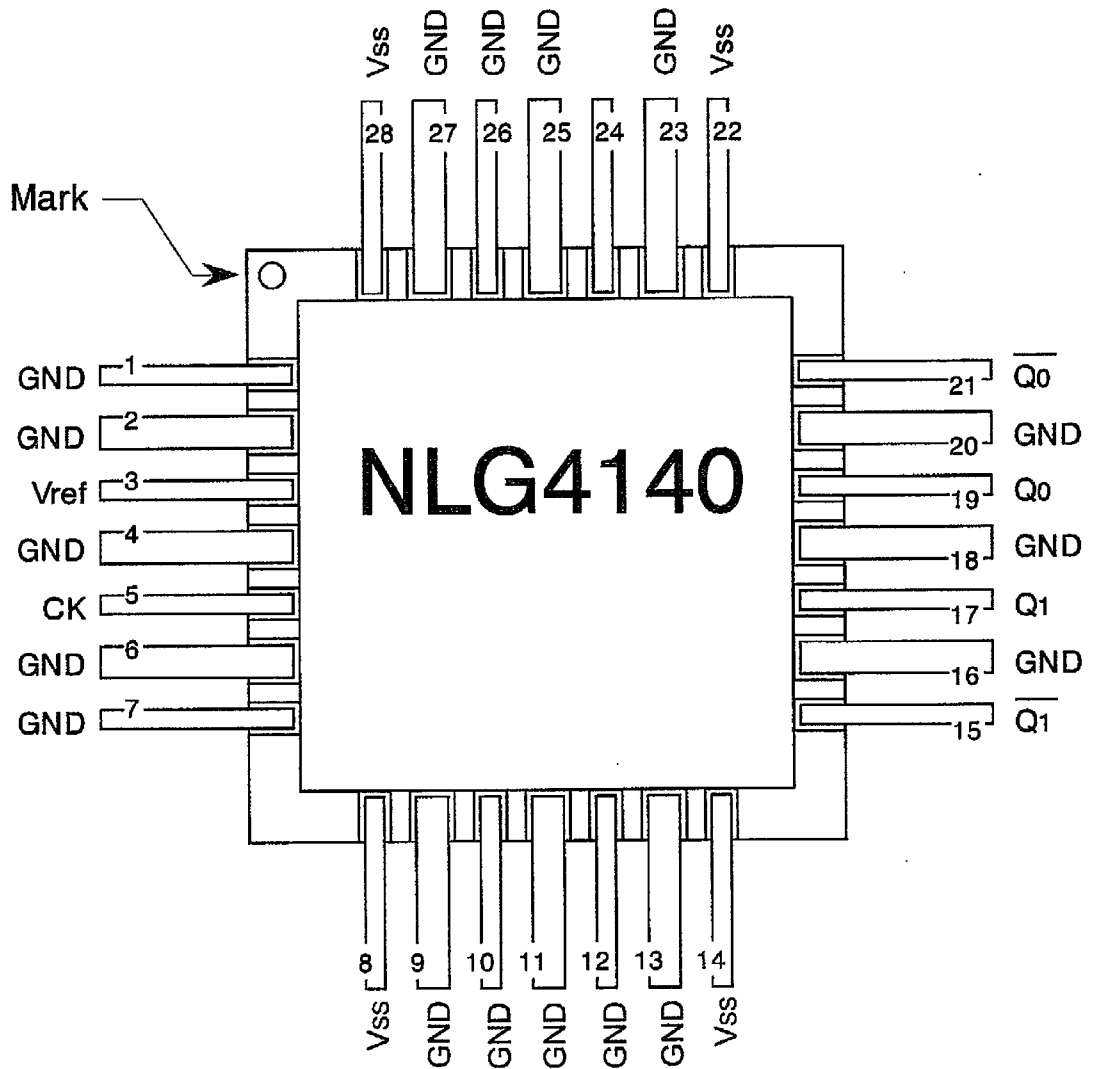
PIN CONNECTION TABLE

PIN No.	NAME	FUNCTION	PIN No.	NAME	FUNCTION
1	GND	Ground (0.0 V)	15	$\overline{Q_1}$	Signal Output 1 (Comp.)
2	GND	Ground (0.0 V)	16	GND	Ground (0.0 V)
3	Vref	Input Ref. ⁽¹⁾	17	Q1	Signal Output 1 (True)
4	GND	Ground (0.0 V)	18	GND	Ground (0.0 V)
5	CK	Clock Input	19	Q0	Signal Output 0 (True)
6	GND	Ground (0.0 V)	20	GND	Ground (0.0 V)
7	GND	Ground (0.0 V)	21	$\overline{Q_0}$	Signal Output 0 (Comp.)
8	Vss	Power Supply (- 3.5 V)	22	Vss	Power Supply (- 3.5 V)
9	GND	Ground (0.0 V)	23	GND	Ground (0.0 V)
10	GND	Ground (0.0 V)	24	NC	No Internal Connection
11	GND	Ground (0.0 V)	25	GND	Ground (0.0 V)
12	GND	Ground (0.0 V)	26	GND	Ground (0.0 V)
13	GND	Ground (0.0 V)	27	GND	Ground (0.0 V)
14	Vss	Power Supply (- 3.5 V)	28	Vss	Power Supply (- 3.5 V)

Notes

- (1) Vref: Internally generated reference voltage that determines the clock input threshold level.
 (2) Terminate unused output pins to GND through 50-ohm resistors.

CONNECTION DIAGRAM (TOP VIEW)



ABSOLUTE MAXIMUM RATINGS

SYMBOL	PARAMETER	RATING
V _{ss}	Power Supply Voltage	+0.5 V ~ -4.0 V
V _{in}	Applied Voltage Amplitude at Clock Input (CK)	1.6 V _{p-p}
V _{inck}	Applied Voltage at Clock Input (CK)	+1.6 V ~ -1.6 V
V _{out}	Applied Voltage at Clock Outputs (Q ₀ , $\overline{Q_0}$, Q ₁ , $\overline{Q_1}$)	+0.2 V ~ -1.75 V
V _{ref}	Applied Voltage at V _{ref} pin under Bias	-1.0 V ~ -2.5 V
T _{stor}	Storage temperature	-60 °C ~ +150 °C
T _c (1)	Case temperature under Bias	-60 °C ~ +125 °C

RECOMMENDED OPERATING CONDITIONS

SYMBOL	PARAMETER	MIN.	TYP.	MAX.	UNITS
V _{ss}	Power Supply Voltage	-3.75	-3.5	-3.4	V
V _{ref}	Clock Input Reference Voltage	Normally Open			V
CK	Clock Input Interface (CK)	DC Coupling or AC Coupling (See AC Characteristics)			—
OUT	Clock Output Interface (Q ₀ , $\overline{Q_0}$, Q ₁ , $\overline{Q_1}$)	DC Coupling or AC Coupling (See AC Characteristics)			—

DC CHARACTERISTICS

(V_{ss} = -3.4 V ~ -3.75 V, GND = 0.0 V, T_c = 0 ~ 85 °C (1))

SYMBOL	PARAMETER	MIN.	TYP.	MAX.	UNITS
I _{ss}	Power Supply Current		410	580	mA (2)
P _d	Power Dissipation		1.4	2.2	W (2)

Notes

- (1) T_c : temperature at package base.
 (2) Includes load current. Excludes current through input termination resistors,
 all of which have a value of 50-ohm resistors.

AC CHARACTERISTICS

($V_{SS} = -3.4\text{ V} \sim -3.75\text{ V}$, $GND = 0.0\text{ V}$, $T_c = 0^\circ\text{C} \sim 85^\circ\text{C}$, $V_{ref} : \text{Open}$)

SYMBOL	PARAMETER	MIN.	TYP.	MAX.	UNITS	
V_{in}	Minimum Input Voltage Amplitude			0.55	VP-P	(4)
V_{center}	Clock Input Center Voltage	-0.5		0.5	V	(4)
f_{MAX}	Maximum Clock Frequency	12.5			GHz	
f_{MIN}	Minimum Clock Frequency			2.0	GHz	
V_{amp}	Output Voltage Amplitude (Q_0 , $\overline{Q_0}$, Q_1 , $\overline{Q_1}$)	0.55	0.90		VP-P	(1), (2) (4)
V_{OH}	Output Voltage, High (Q_0 , $\overline{Q_0}$, Q_1 , $\overline{Q_1}$)	-0.20	-0.05		V	(3), (4)
V_{OL}	Output Voltage, Low (Q_0 , $\overline{Q_0}$, Q_1 , $\overline{Q_1}$)		-1.10	-0.75	V	(3), (4)
t_r	Output Rise Time (Q_0 , $\overline{Q_0}$, Q_1 , $\overline{Q_1}$)		15	25	ps	(1), (4)
t_f	Output Fall Time (Q_0 , $\overline{Q_0}$, Q_1 , $\overline{Q_1}$)		15	25	ps	(1), (4)
t_{dLH}	Output Rise Delay (CK - Q_n , $\overline{Q_n}$)	190	220	250	ps	(4)
t_{dHL}	Output Fall Delay (CK - Q_n , $\overline{Q_n}$)	190	220	250	ps	(4)

Notes

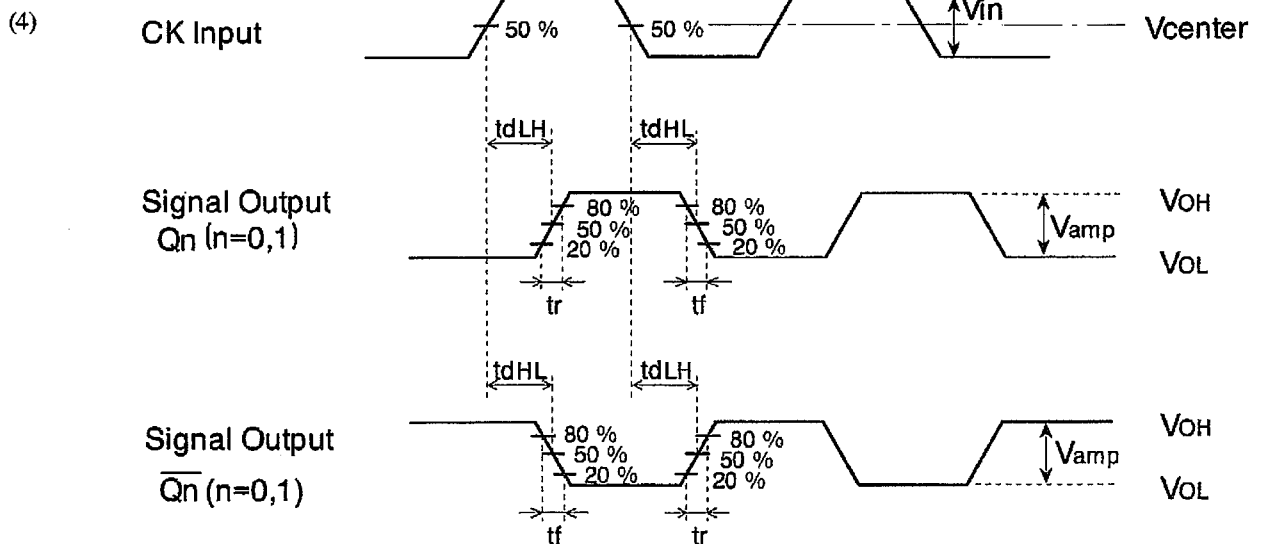
(1) Measurement Condition : $f = 12.5\text{ GHz}$

(2) AC coupling 50Ω to GND

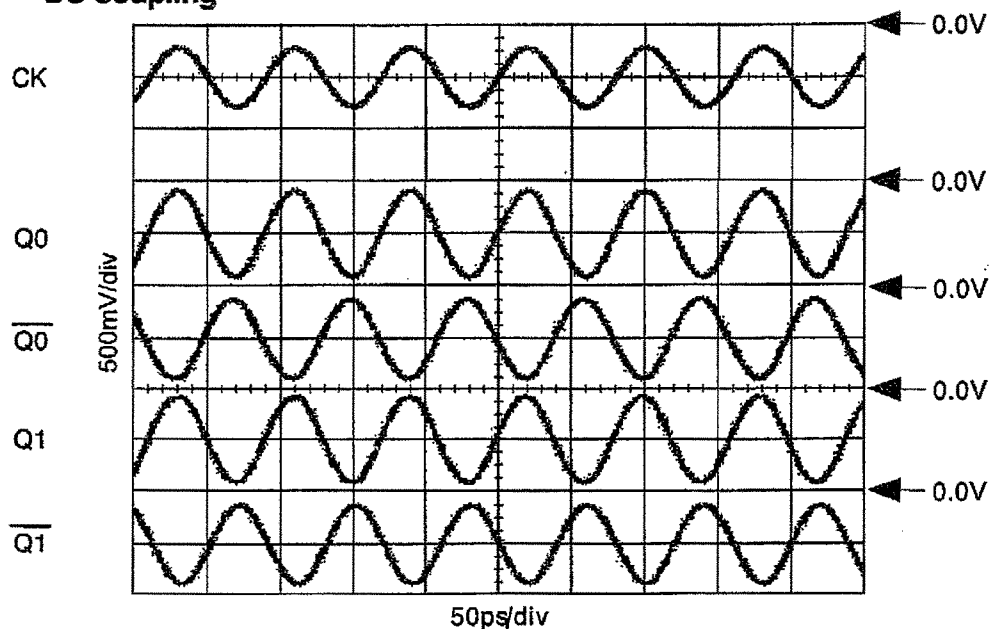
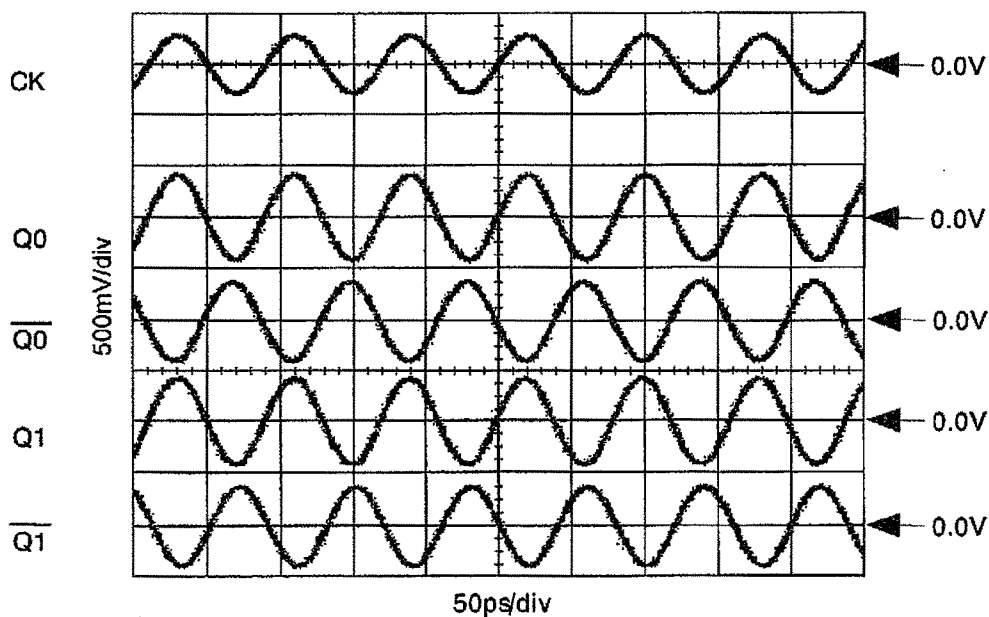
DC Block : Picosecond Pulse Labs. , Model 5501A

(3) DC coupling 50Ω to GND

Measurement Condition : $f = 2.0\text{ GHz}$



SAMPLE INPUT AND OUTPUT WAVEFORMS (12.5GHz)

DC Coupling**AC Coupling**

output signal jitters = 1.45 psrms

Measurement Conditions

$T_c = 35^\circ\text{C}$

$V_{ss} = -3.5\text{V}$

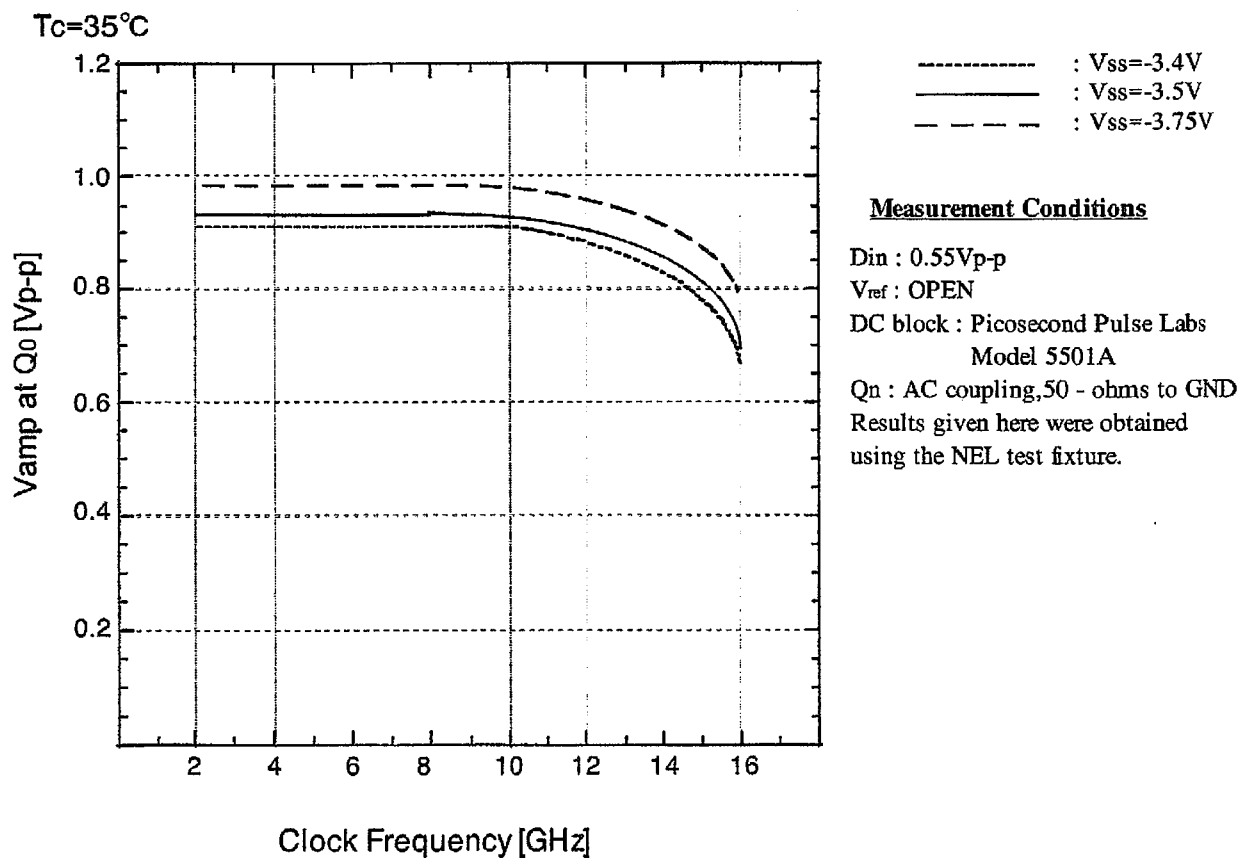
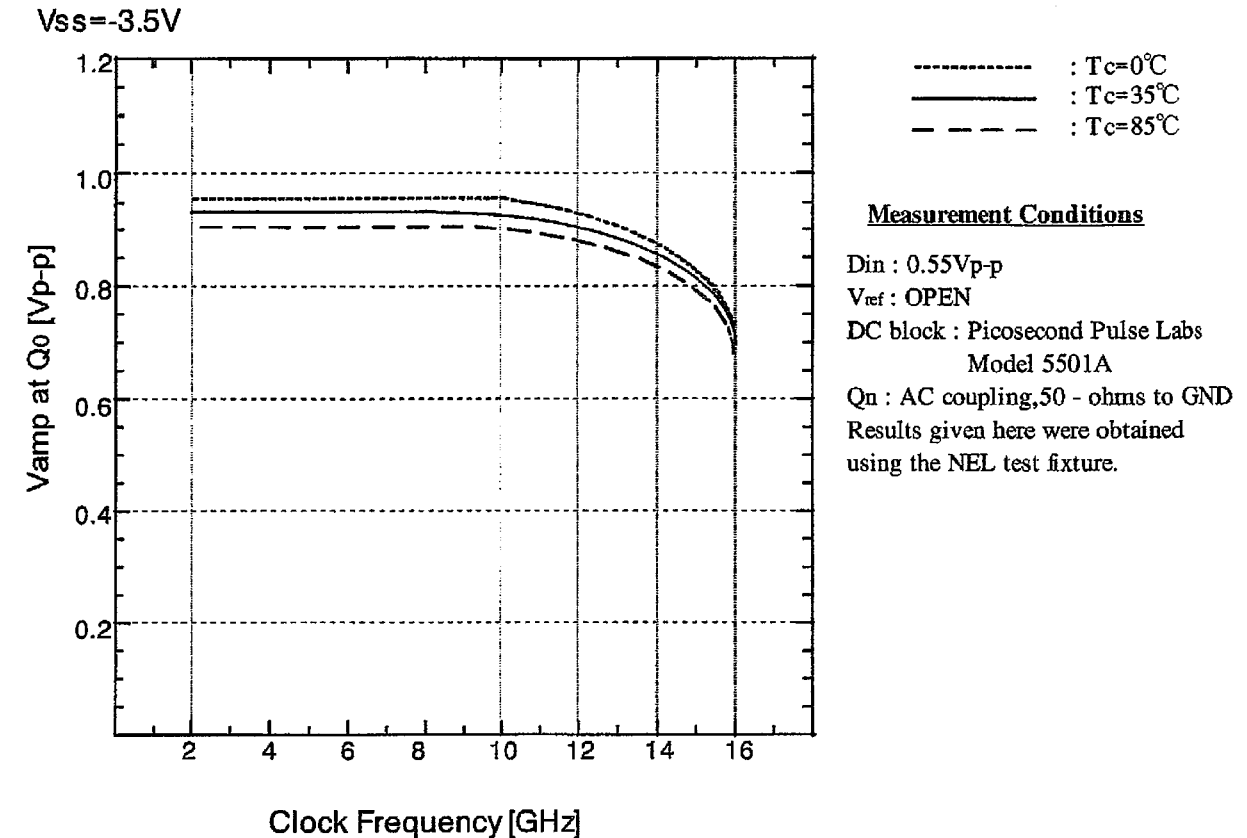
V_{ref} : OPEN

Clock input signal jitter = 1.23 psrms

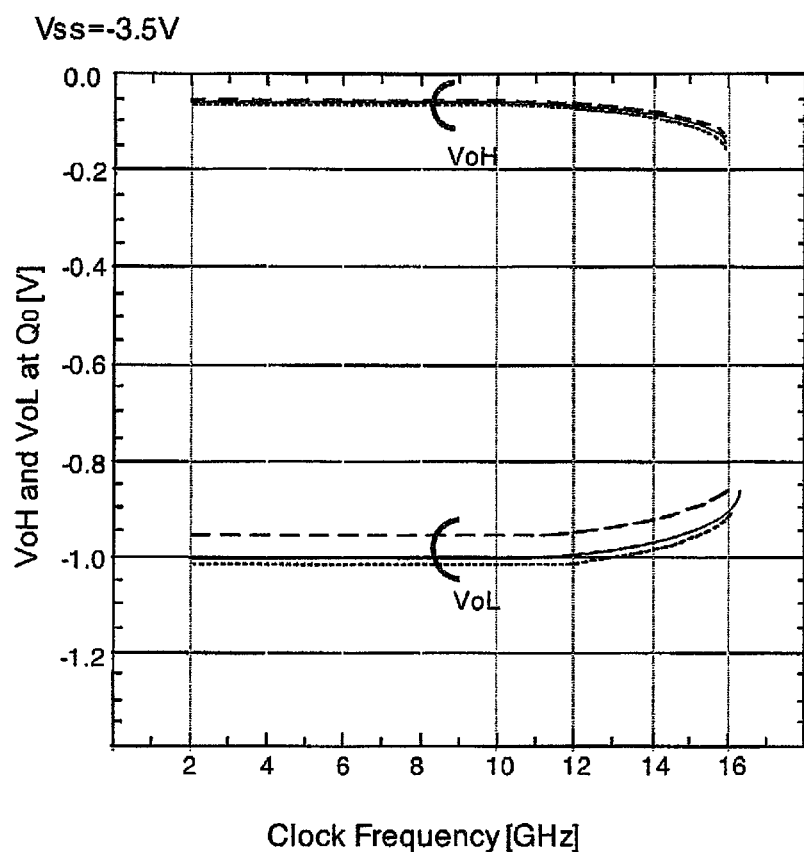
Clock outputs connected to the 50-ohm impedance pins of a sampling oscilloscope.

Results given here were obtained using the NEL test fixture

SAMPLE AC CHARACTERISTICS (AC coupling)



SAMPLE AC CHARACTERISTICS (DC coupling)

Measurement Conditions

Din : 0.55Vp-p

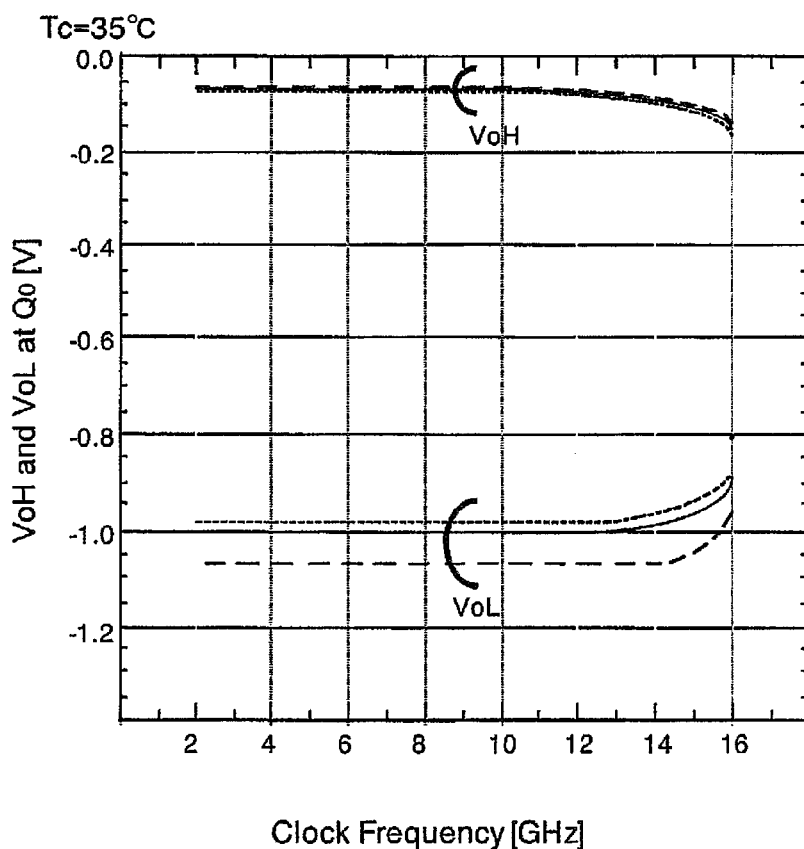
Vref : OPEN

DC block : Picosecond Pulse Labs

Model 5501A

Qn : DC coupling, 50 - ohms to GND

Results given here were obtained using the NEL test fixture.

Measurement Conditions

Din : 0.55Vp-p

Vref : OPEN

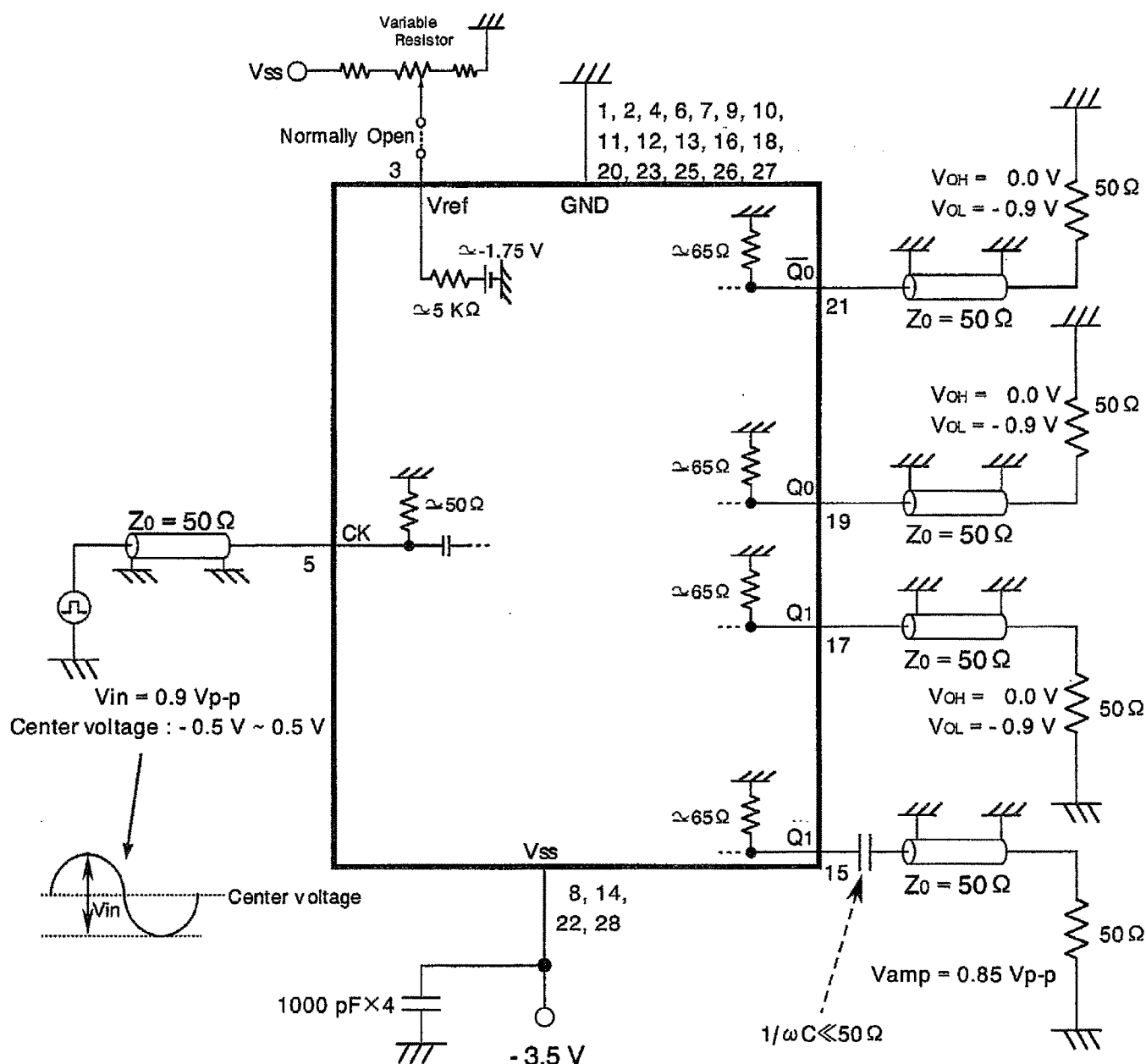
DC block : Picosecond Pulse Labs

Model 5501A

Qn : DC coupling, 50 - ohms to GND

Results given here were obtained using the NEL test fixture.

SAMPLE IMPLEMENTATION



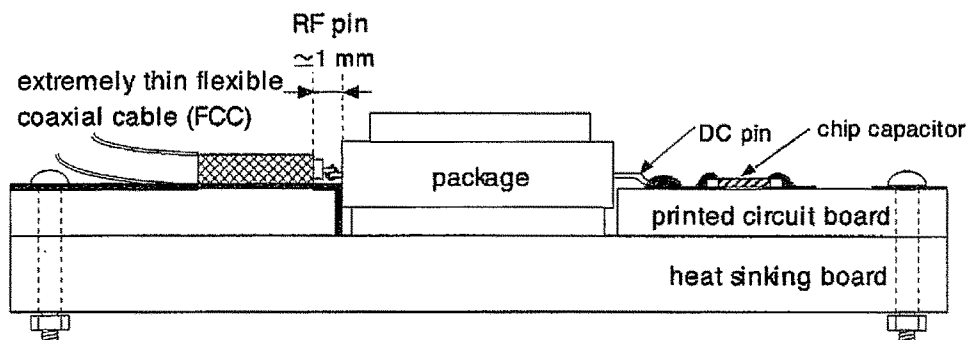
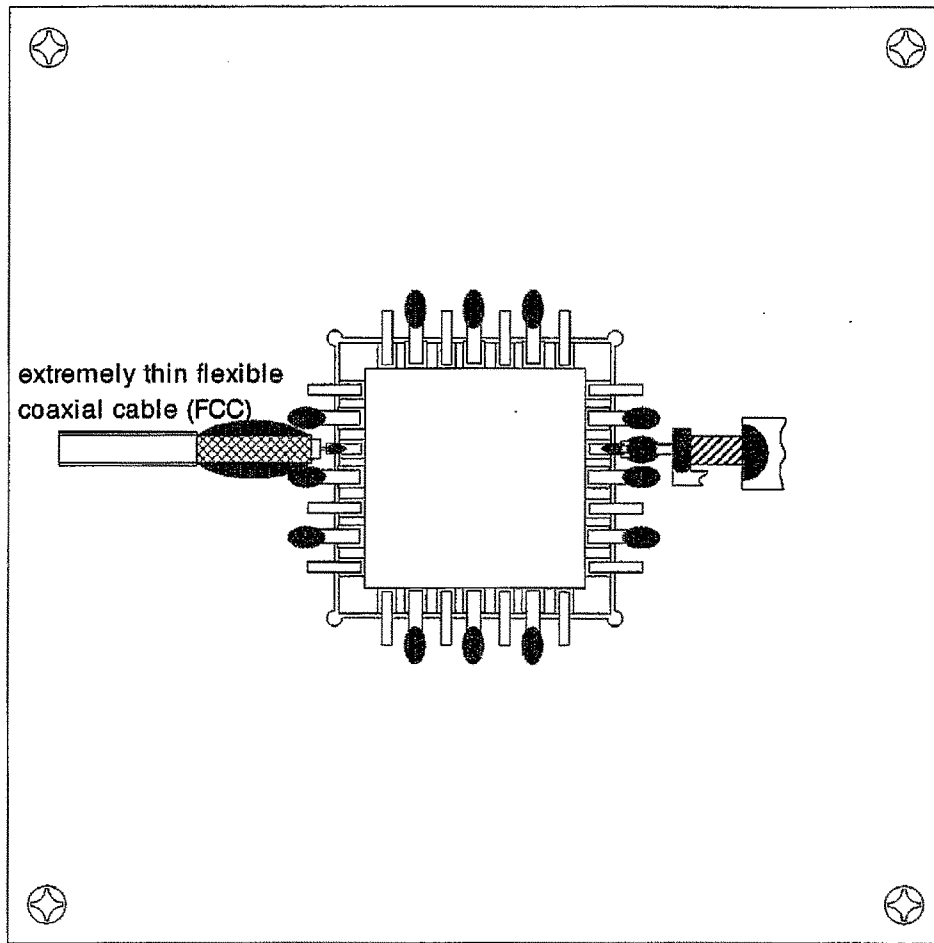
Notes

- (1) Numbers represent pin numbers
- (2) Either AC coupling or DC coupling can be used for all outputs ($Q0$, $\overline{Q0}$, $Q1$, $\overline{Q1}$).
- (3) AC coupling capacitor is necessary outside the NLG4140 ($Q0$, $\overline{Q0}$, $Q1$, $\overline{Q1}$).

Although not shown here, in place of the above variable resistor, the Vref pin can be connected directly to an external power supply.

In this case, apply approximately -1.75 V to the Vref pin.

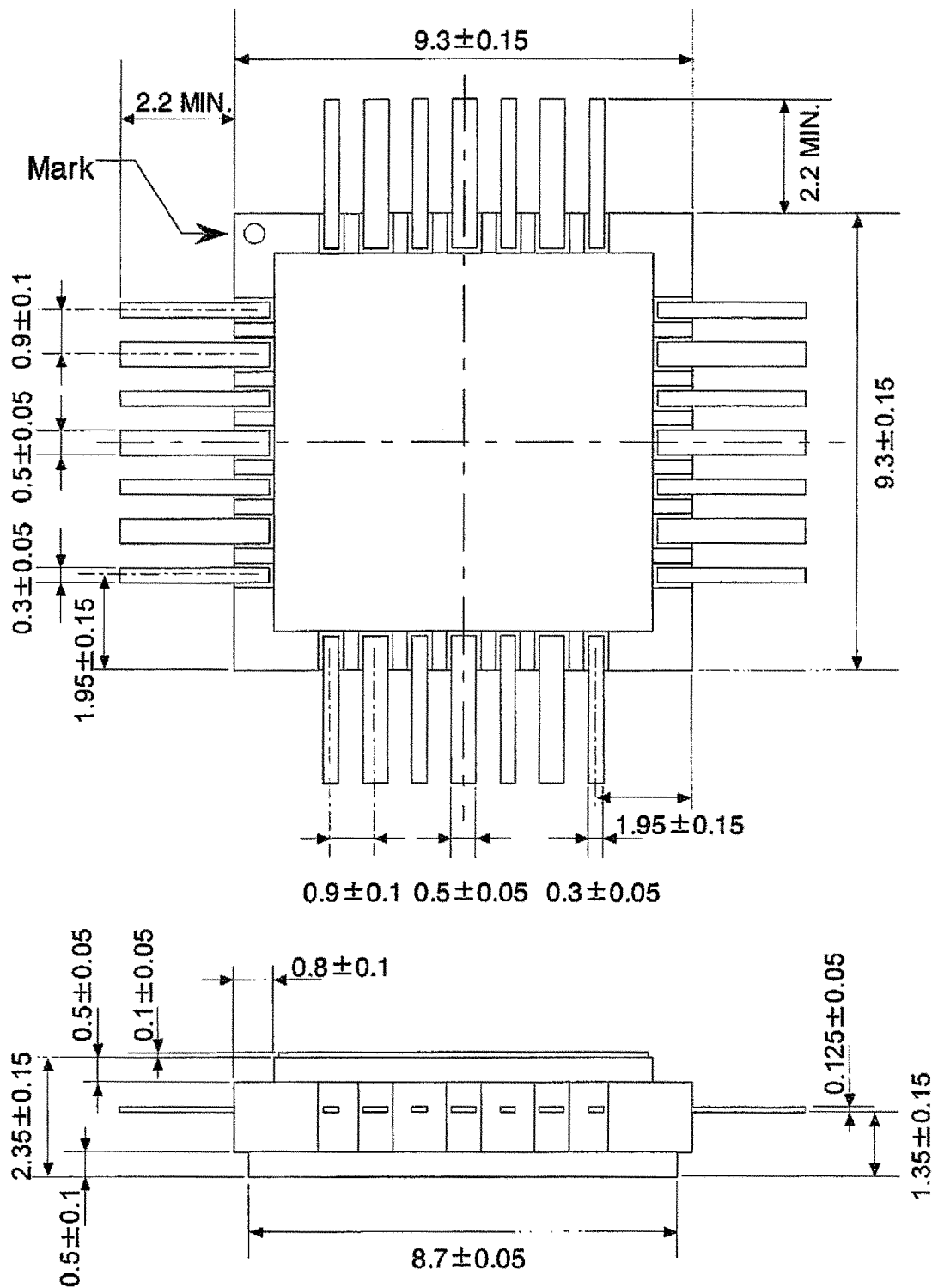
SAMPLE MOUNTING



 : solder

Caution : The package base should be connected to the ground.

TB 28 - PIN PACKAGE DIMENSION (mm)



HANDLING INSTRUCTIONS

Since the NLG4140 is fabricated with GaAs MESFET's (Metal Semiconductor Field Effect Transistors), users are recommended to follow the instructions below to prevent damage to the chip from electro-static discharge.

- 1) Use a conductive working desk connected to the ground (or, a conductive table top connected to the ground).
- 2) Require all handling personnel to wear a conductive bracelet or wrist-strap connected to the ground through a 1 M-ohm resistors.
- 3) Ground all test equipment.
- 4) Ground all soldering iron tips.
- 5) Store IC's and other devices such as chip capacitors in their conductive carriers until they are soldered.

Caution

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